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25A, 600V - 1000V Glass Passivated Bridge Rectifier

FEATURES

- Glass passivated junction
- Ideal for printed circuit board
- High surge current capability
- UL Recognized File # E-326243
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- TV
- Monitor

MECHANICAL DATA

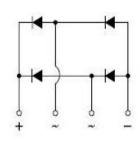
- Case: TS-6P
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Polarity: As marked
- Mounting torque: 0.92 N·m maximum
- Weight: 6.5 g (approximately)

| KEY PARAMETERS | | |
|--------------------|------------|------|
| PARAMETER | VALUE | UNIT |
| I _F | 25 | А |
| V _{RRM} | 600 - 1000 | V |
| I _{FSM} | 350 | А |
| T _{J MAX} | 150 | °C |
| Package | TS-6P | |
| Configuration | Quad | |









| ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted) | | | | | |
|---|---------------------|-----------------------|-----------------------|-----------------------|------|
| PARAMETER | SYMBOL | TS25P | TS25P | TS25P | UNIT |
| Marking code on the device | | 05G-K TS25P 05G | 06G-K TS25P 06G | 07G-K TS25P 07G | |
| Repetitive peak reverse voltage | V _{RRM} | 600 | 800 | 1000 | V |
| Reverse voltage, total rms value | V _{R(RMS)} | 420 | 560 | 700 | V |
| Forward current | I _F | | 25 | | А |
| Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode | I _{FSM} | 350 | | A | |
| Rating of fusing (t<8.3ms) | l ² t | 508 | | A ² s | |
| Junction temperature | TJ | - 55 to +150 | | °C | |
| Storage temperature | T _{STG} | - 55 to +150 | | °C | |



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| PARAMETER | SYMBOL | ТҮР | UNIT |
|-------------------------------------|------------------|-----|------|
| Junction-to-case thermal resistance | R _{eJC} | 1.3 | °C/W |

Thermal Performance Note: Ideal heat sink

| ELECTRICAL SPECIFICATIONS ($T_A = 25^{\circ}C$ unless otherwise noted) | | | | | |
|--|--|------------------|-----|-----|------|
| PARAMETER | CONDITIONS | SYMBOL | ТҮР | MAX | UNIT |
| Forward voltage per diode (1) | $I_F = 12.5A, T_J = 25^{\circ}C$ | V _F | - | 1.1 | V |
| | I _F = 12.5A, T _J = 125°C | | - | 1.0 | V |
| Reverse current @ rated V_R per diode $^{(2)}$ | $T_A = 25^{\circ}C$ | - I _R | - | 10 | μA |
| | T _A = 125°C | | - | 500 | μA |
| Junction capacitance | 1 MHz, V _R =4.0V | CJ | 119 | - | pF |

Notes:

1. Pulse test with PW=0.3 ms

2. Pulse test with PW=30 ms

| ORDERING INFORMATION | | |
|-----------------------------|---------|-----------|
| ORDERING CODE (Note 1,2) | PACKAGE | PACKING |
| TS25P0xG-K C7 | TS-6P | 15 / TUBE |
| TS25P0xG-K C7G | TS-6P | 15 / TUBE |

Note 1:

"x" defines voltage from 600V (TS25P05G-K) to 1000V (TS25P07G-K)

Note 2:

"G" means green compound (halogen free)



Fig.2 Typical Junction Capacitance

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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

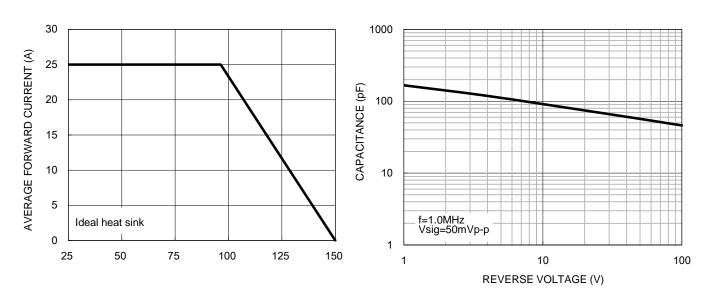
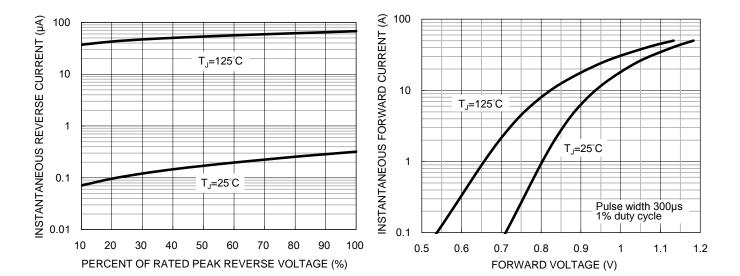


Fig.1 Forward Current Derating Curve



Fig.4 Typical Forward Characteristics

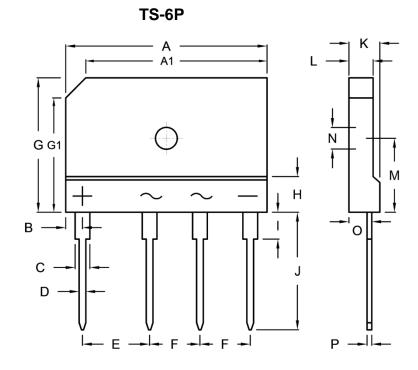




TS25P05G-K - TS25P07G-K

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PACKAGE OUTLINE DIMENSIONS



| DIM. | Unit (mm) | | Unit (| (inch) |
|-------|-----------|-------|--------|--------|
| Divi. | Min. | Max. | Min. | Max. |
| А | 29.70 | 30.30 | 1.169 | 1.193 |
| A1 | 26.50 | 27.50 | 1.043 | 1.083 |
| В | 2.30 | 2.70 | 0.091 | 0.106 |
| С | 2.00 | 2.40 | 0.079 | 0.094 |
| D | 0.90 | 1.10 | 0.035 | 0.043 |
| E | 9.80 | 10.20 | 0.386 | 0.402 |
| F | 7.30 | 7.70 | 0.287 | 0.303 |
| G | 19.70 | 20.30 | 0.776 | 0.799 |
| G1 | 16.50 | 17.50 | 0.650 | 0.689 |
| н | 4.80 | 5.80 | 0.189 | 0.228 |
| I | 3.80 | 4.20 | 0.150 | 0.165 |
| J | 17.00 | 18.00 | 0.669 | 0.709 |
| к | 4.40 | 4.80 | 0.173 | 0.189 |
| L | 3.40 | 3.80 | 0.134 | 0.150 |
| м | 10.80 | 11.20 | 0.425 | 0.441 |
| N | 3.10 | 3.40 | 0.122 | 0.134 |
| 0 | 3.10 | 3.70 | 0.122 | 0.146 |
| Р | 0.60 | 0.80 | 0.024 | 0.031 |

MARKING DIAGRAM



| P/N | = Marking Code |
|-----|------------------|
| G | = Green compound |
| YWW | = Date Code |
| F | = Factory Code |



<u>TS25P05G-K - TS25P07G-K</u>

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